

### 120V N-Ch Power MOSFET

#### Feature

- ◇ High Speed Power Smooth Switching
- ◇ Enhanced Body diode dv/dt capability
- ◇ Enhanced Avalanche Ruggedness
- ◇ 100% UIS Tested, 100% Rg Tested
- ◇ Lead Free

#### Application

- ◇ Synchronous Rectification in SMPS
- ◇ Hard Switching and High Speed Circuit
- ◇ Power Tools
- ◇ UPS
- ◇ Motor Control

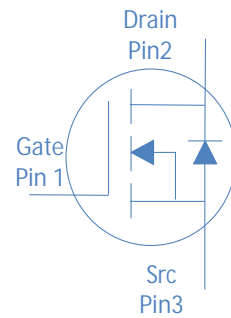
$V_{DS}$	120	V
$R_{DS(on),TYP}$	3.6	m $\Omega$
$I_D$ (Silicon Limited)	197	A
$I_D$ (Package Limited)	180	A

Part Number	Package	Marking
HGB039N12S	TO-263	GB039N12S
HGK039N12S	TO-247	GK039N12S
HGP039N12S	TO-220	GP039N12S

TO-263

TO-220

TO-247



#### Absolute Maximum Ratings at $T_j=25$ (unless otherwise specified)

Parameter	Symbol	Conditions	Value	Unit
Continuous Drain Current (Silicon Limited)	$I_D$	$T_C=25$	197	A
		$T_C=100$	139	
		$T_C=25$	180	
Continuous Drain Current (Package Limited)		$T_C=25$	180	
Drain to Source Voltage	$V_{DS}$	-	120	V
Gate to Source Voltage	$V_{GS}$	-	$\pm 20$	V
Pulsed Drain Current	$I_{DM}$	-	550	A
Avalanche Energy, Single Pulse	$E_{AS}$	$L=0.4mH, T_C=25$	720	mJ
Power Dissipation	$P_D$	$T_C=25$	357	W
Operating and Storage Temperature	$T_J, T_{stg}$	-	-55 to 175	

#### Absolute Maximum Ratings

Parameter	Symbol	Max	Unit
Thermal Resistance Junction-Case	$R_{JC}$	0.42	$\text{mW}$
Thermal Resistance Junction-Ambient	$R_{JA}$	60	$\text{mW}$

Electrical Characteristics at  $T_j=25$  (unless otherwise specified)

			min	typ	max	
Drain to Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS}=0V, I_D=250\mu A$	120	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{GS}=V_{DS}, I_D=250\mu A$		3	4	
		$V_{GS}=0V, V_{DS}=120V, T_j=100$	-	-	100	$\mu A$



Figure 7. Typical Gate-Charge vs. Gate-to-Source Voltage

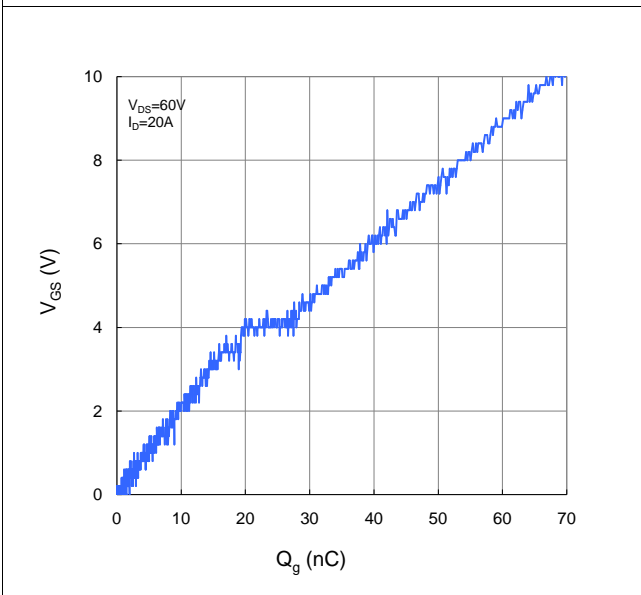


Figure 8. Typical Capacitance vs. Drain-to-Source Voltage

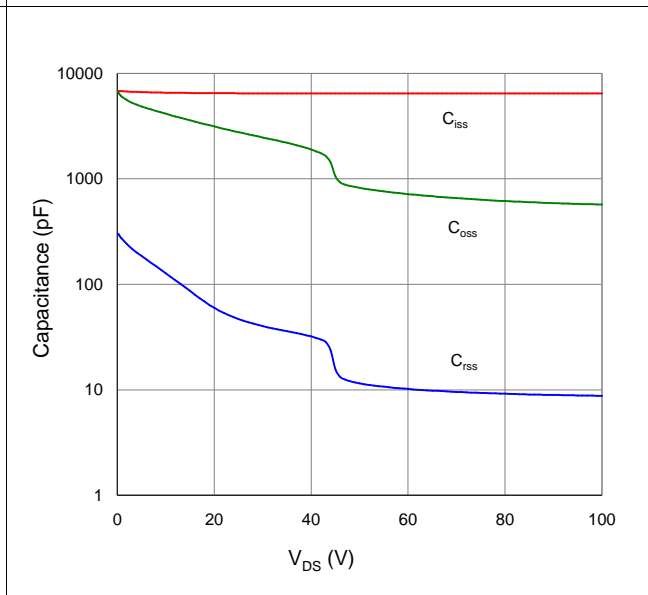


Figure 9. Maximum Safe Operating Area

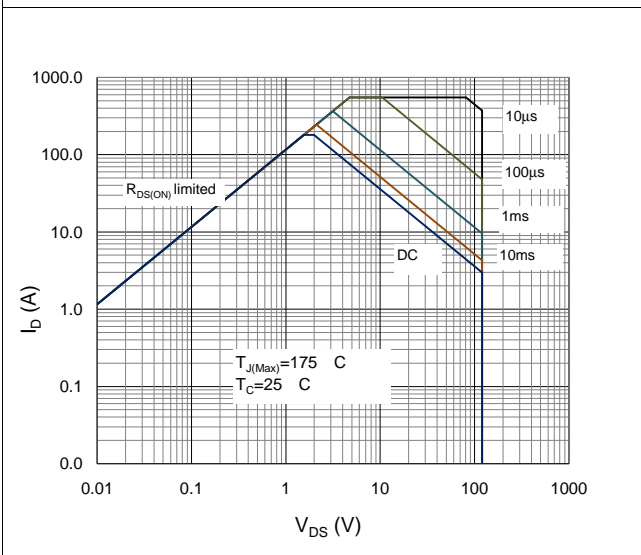


Figure 10. Maximum Drain Current vs. Case Temperature

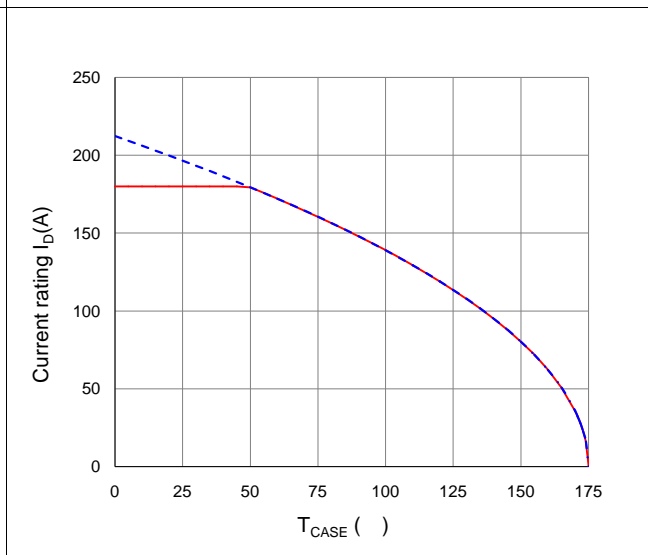
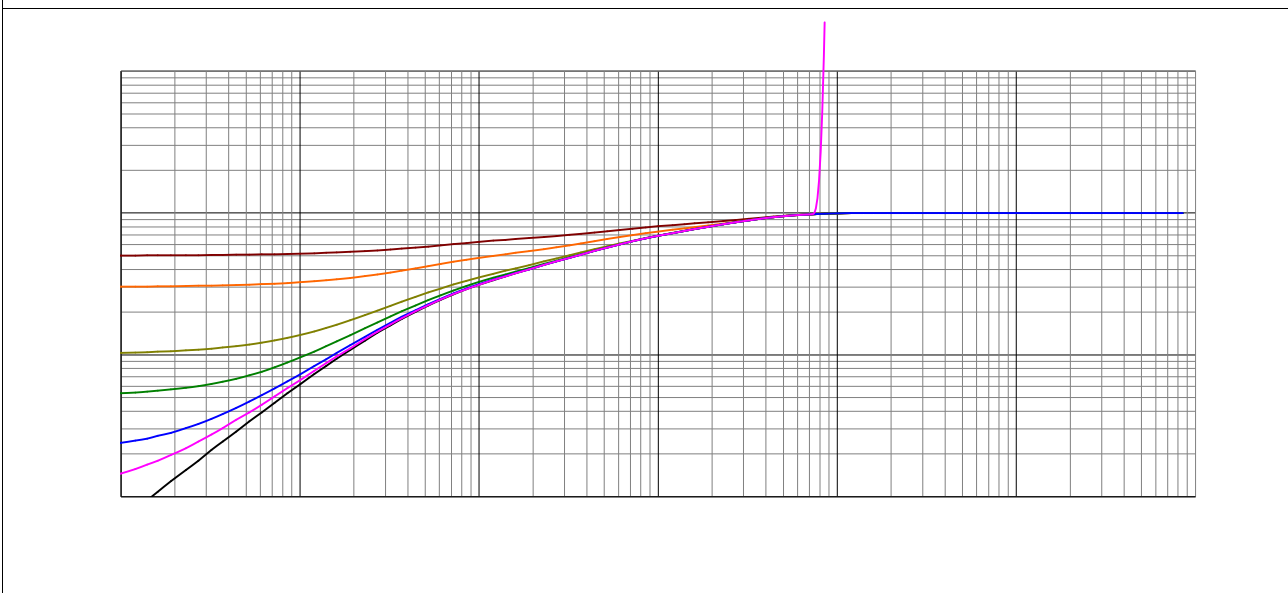
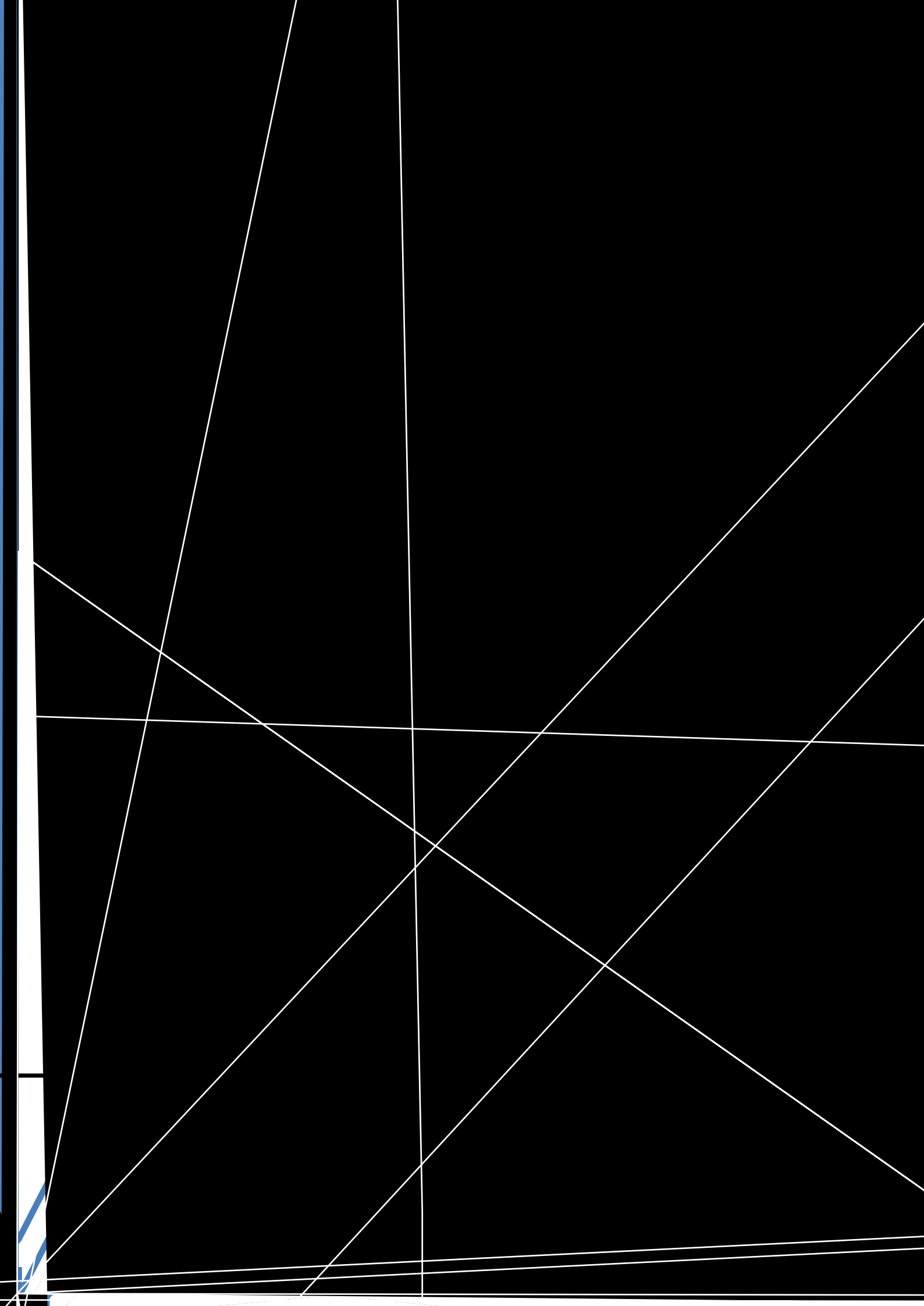


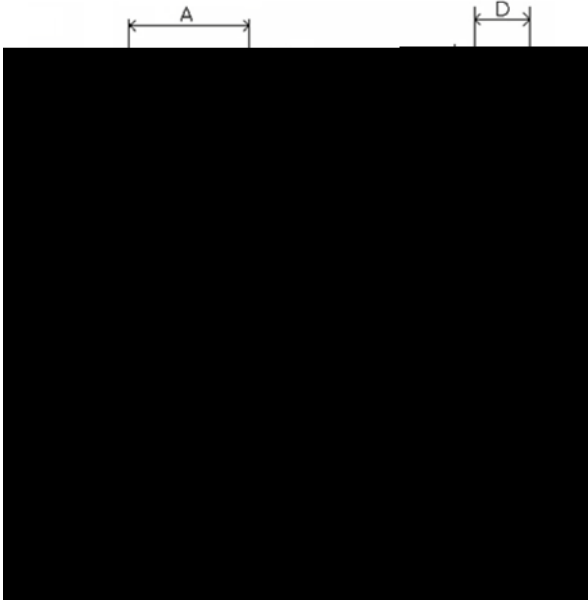
Figure 11. Normalized Maximum Transient Thermal Impedance, Junction-to-Case





TO-220, 3 leads

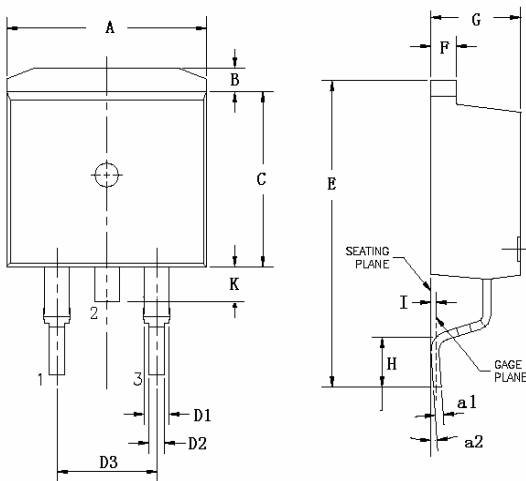
Dimensions in mm unless otherwise specified



Symbol	Min	Nom	Max
A	9.66	9.97	10.28
A2	9.80	10.00	10.20
B	15.60	15.70	15.80
C	12.70	13.48	14.27
D	4.30	4.50	4.70
E	9.00	9.20	9.40
F		2.54	
G1	1.32	1.52	1.72
G2	0.70	0.82	0.95
G3	0.45	0.52	0.60
H	3.50	3.60	3.70
I	2.70	2.80	2.90
J	15.70	15.97	16.25
K	2.20	2.40	2.60
L	1.15	1.27	1.40
N	6.40	6.60	6.80

TO-263, 2 leads

Dimensions in mm unless otherwise specified



Symbol	Min	Nom	Max
A	9.66	9.97	10.28
B	1.02	1.17	1.32
C	8.59	9.00	9.40
D1	1.14	1.27	1.40
D2	0.70	0.83	0.95
D3		5.08	
E	15.09	15.24	15.39
F	1.15	1.28	1.40
G	4.30	4.50	4.70
H	2.29	2.54	2.79
I		0.25	
K	1.30	1.45	1.60
a1	0.45	0.55	0.65
a2(degree)	0°		8°



HGB039N12S , HGK039N12S  
HGP039N12S

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TO-247, 3 leads